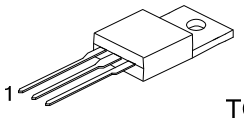
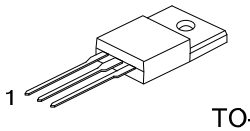
TIP41C

NPN PLANAR TRANSISTOR

NPN EXPITAXIAL PLANAR TRANSISTOR



TO-220



TO-220F

■ DESCRIPTION

The UTC TIP41C is a NPN expitaxial planar transistor, designed for using in general purpose amplifier and switching applications.

■ FEATURE

* Complement to TIP42C

■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
TIP41CL-TA3-T	TIP41CG-TA3-T	TO-220	B	C	E	Tube
TIP41CL-TF3-T	TIP41CG-TF3-T	TO-220F	B	C	E	Tube

TIP41CL-TA3-T

(1)Packing Type — (1) T: Tube

(2)Package Type — (2) TA3: TO-220, TF3: TO-220F

(3)Lead Free — (3) G: Halogen Free, L: Lead Free

■ ABSOLUTE MAXIMUM RATINGS (T_C=25°C, unless otherwise specified)

PARAMETER			SYMBOL	RATING	UNIT
Collector Base Voltage			V_{CBO}	100	V
Collector to Emitter Voltage			V_{CEO}	100	V
Emitter-Base Voltage			V_{EBO}	5	V
Collector Current		DC	I_C	6	A
		Pulse		10	A
Base Current			I_B	2	A
Collector Dissipation	T_C=25°C	TO-220	P_C	65	W
		TO-220F		22	
	T_A=25°C	TO-220		2	W
		TO-220F		0.7	
Junction Temperature			T_J	150	°C
Storage Temperature			T_{STG}	-65 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS (T_C=25°C)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector Emitter Sustaining Voltage (Note)	V_{CEO}	I_C=30mA, I_B=0	100			V
Collector Cutoff Current	I_{CEO}	V_{CE}=60V, I_B=0			0.7	mA
Collector Cutoff Current	I_{CES}	V_{CE}=100V, V_{EB}=0			400	μA
Emitter Cutoff Current	I_{EBO}	V_{EB}=5V, I_C=0			1	mA
Collector-Emitter Saturation Voltage (Note)	$V_{CE(SAT)}$	I_C=6A, I_B=600mA			1.5	V
Base-Emitter On Voltage (Note)	$V_{BE(ON)}$	I_C=6A, V_{CE}=4V			2.0	V
DC Current Gain (Note)	h_{FE1}	I_C=300mA, V_{CE}=4V	30			
	h_{FE2}	I_C=3A, V_{CE}=4V	15		75	
Current Gain Bandwidth Product	f_T	V_{CE}=10V, I_C=500mA, f=1MHz	3			MHz

Note: Pulse Test: P_W≦300μs, Duty Cycle≦2%

■ TYPICAL CHARACTERISTICS